# Nucleation Stage for the Oriented Growth of Tantalum Sulfide Monolayers on $\mathrm{Au}(111)$ 

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We study the nucleation stage in the epitaxial growth of monolayer $\mathrm{TaS}_{2}$ as a model system for monolayer transition metal sulfides [1]. The growth was done under ultra-high vacuum conditions with $\mathrm{Au}(111)$ as a substrate on which the metal atoms are evaporated, and the sulfur is provided from a background of $\mathrm{H}_{2} \mathrm{~S}$. Using scanning tunneling microscopy (STM), we find atomic-scale protrusions with a well-defined triangular shape that act as nuclei for the further growth of extended tantalum sulfide monolayers (figure 1, left panel). We identify these protrusions as $\mathrm{TaS}_{3}$ (figure 1, right panel) using density functional theory (DFT). We propose that their unique orientation is the cause of the welldefined orientation of a complete $\mathrm{TaS}_{2}$ layer found under favorable growth conditions [2].


Fig. 1. (Left panel) Atomically-resolved STM topographic image of the protrusions (appearing as three dots) on $\mathrm{Au}(111)$. Image parameters: $1.9 \mathrm{~nm} \times 1.9 \mathrm{~nm}, U=-0.3 \mathrm{~V}, I=2.3 \mathrm{nA}$. (Right panel) Structural configuration of $\mathrm{TaS}_{3}$ (top view) with a Ta atom (shown in blue) embedded in the $\mathrm{Au}(111)$ substrate (shown in gold) and connected to three $S$ atoms (shown in yellow).
[1] Chagas, T., Mehlich, K., Samad, A., Grover, C., Dombrowski, D., Cai, J., Schwingenschlögl, U., Busse, C. J. Phys. Chem. C, 127, 5622 (2023). DOI: 10.1021/acs.jpcc.3c00234
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